



A-9837E  
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Lars Ivar SAMUELSON et al.

Appln. No.: 10/613,071

Group Art Unit: 2811

Filed: July 7, 2003

For: NANOSTRUCTURES AND METHODS FOR MANUFACTURING  
THE SAME

\* \* \*

INFORMATION DISCLOSURE STATEMENT

Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Pursuant to 37 C.F.R. § 1.56, and without any assertion as to materiality or prior art effect, the documents listed on the attached Form PTO-1449 are hereby cited.

Documents AA-AB, AE, AJ, AO, QD, and TH-TK on the attached List were cited in the International Search Report (copy attached) of counterpart PCT Application No.

PCT/GB2004/000037.

Respectfully submitted,

MWS:lmb


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September 29, 2004

<b>FORM PTO-1449</b>				<b>Atty. Docket No.</b> A-9837E		<b>Appln. No.</b> 10/613,071	
<b><u>LIST OF DOCUMENTS CITED BY APPLICANT</u></b>							
				<b>Applicant</b> Lars Ivar SAMUELSON et al.			
				<b>Filing Date</b> July 7, 2003		<b>Group</b> 2811	
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	BA	6,190,634	2/20/01	Lieber et al.	423	439	
	BB	6,159,742	12/12/00	Lieber et al.	436	164	
	BC	5,997,832	12/7/99	Lieber et al.	423	249	
	BD	5,840,435	11/24/98	Lieber et al.	428	689	
	BE	5,252,835	10/12/93	Lieber et al.	250	492.1	
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	BG	Duan, X., et al., "Laser-Assisted Catalytic Growth of Single-Crystal Compound Semiconductor Nanowires", <u>Abstracts of Papers of the Amer. Chem. Soc.</u> , Vol. 219, March 26, 2000, pp. 676-Inor Part 1.					
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	BL	Duan, X. et al., "General Synthesis of Compound Semiconductor Nanowires", <u>Advanced Materials</u> , Vol. 12, No. 4, January 1, 2000, pp. 298-302.					
	BM	Duan, X., et al., "Synthesis and optical properties of gallium arsenide nanowires", <u>Applied Physics Letters</u> , Vol. 76, No. 9, February 28, 2000, pp. 1116-1118.					
	BN	Cui, Y., et al., "Diameter-controlled synthesis of single-crystal silicon nanowires", <u>Applied Physics Letters</u> , Vol. 78, No. 15, April 9, 2001, pp. 2214-2216.					
<b>EXAMINER:</b> Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							

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	AA	2002/0172820	11/21/02	Majumdar et al.	428	357	
	AB	2002/0129761	9/19/02	Takami	117	73	
	AC	5,362,972	11/8/94	Yazawa et al	257	13	
	AD	5,332,910	7/26/94	Haraguchi et al.	257	13	
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	AE	WO 01/84238	11/8/01	WIPO			
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	AF	Yasawa, M. et al, "Heteroepitaxial Ultrafine Wire-Like Growth of InAs on GaAs Substrates", <u>Appl. Phys. Lett.</u> , Vol. 58, No. 10, March 11, 1991, pp. 1080-1082.					
	AG	Haraguchi, K. et al., "GaAs p-n junction formed in quantum wire crystals", <u>Applied Physics Letters</u> , Vol. 60, No. 6, February 10, 1992, pp. 745-747					
	AH	Yazawa, M., et al., "Effect of one monolayer of surface gold atoms on the epitaxial growth of InAs nanowhiskers", <u>Applied Physics Letters</u> , Vol. 61, October 26, 1992, pp. 2051-2053.					
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	CA	6,307,241	10/23/01	Awschalom et al.	257	421	
	CB	5,196,396	3/23/93	Lieber	505	1	
	CC	6,716,409	4/6/04	Hafner et al.	423	447	
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	CD	WO 03/005450	1/16/03	WIPO			
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*	CE	Gudiksen M.S., et al., "Diameter-selective synthesis of semiconductor nanowires", <u>J. Am. Chem. Soc.</u> , Vol. 122, August 22, 2000, pp. 8801-8802.					
	CF	Gudiksen M., et al., "Size-Dependent Photoluminescence from Single Indium Phosphide Nanowires", <u>Journal of Physical Chemistry B</u> , Vol. 106, No. 16, March 30, 2002, pp. 4036-4039.					
*	CG	Duan, X., et al., "Laser-Assisted Catalytic Growth of Single Crystal GaN Nanowires", <u>Journal of Amer. Chem. Soc.</u> , Vol. 122, NO. 1, December 18, 1999, pp. 188-189.					
	CH	Huang, Y., et al., "Gallium Nitride Nanowire Nanodevices", <u>Nano Letters</u> , Vol. 2, No. 2, January 11, 2002, pp. 81-82.					
	CI	Lieber C., "Nanowire Superlattices", <u>Nano Letters</u> , Vol. 2, No. 2, January 25, 2002, pp. 82-82.					
	CJ	Duan, X., et al., "Nonvolatile Memory and Programmable Logic from Molecule-Gated Nanowires", <u>Nano Letters</u> , Vol. 2, No. 5, May 1, 2002, pp. 487-490.					
	CK	Cui, Y., et al., "High Performance Silicon Nanowire Field Effect Transistors", <u>Nano Letters</u> , Vol. 3, No. 2, January 1, 2003, pp. 149-152.					
	CL	Zhong, Z., et al., "Synthesis of P-Type Gallium Nitride Nanowires for Electronic and Photonic Nanodevices", <u>Nano Letters</u> , Vol. 3, No. 3, February 20, 2003, pp. 343-346.					
*	CM	Hu, J., et al., "Controlled Growth and Electrical Properties of Heterojunctions of Carbon Nanotubes and Silicon Nanowires", <u>Nature</u> , Vol. 399, May 6, 1999, pp. 48-51.					
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\* PTO did not received

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	DA	6,743,408	6/1/04	Lieber et al.	423	447.1	
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	DB	WO 01/03208	1/11/01	WIPO			
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	DD	Gudiksen M., et al., "Growth of nanowire superlattice structures for nanoscale photonics and electronics", <u>Nature</u> , Vol. 415, February 7, 2002, pp. 617-620.					
	DE	Lauhon, L., et al., "Epitaxial Core-Shell and Core-Multishell Nanowire Heterostructures", <u>Nature</u> , Vol. 420, No. 6911, November 7, 2002, pp. 57-61.					
	DF	Duan, X., "Single-nanowire electrically driven lasers", <u>Nature</u> , Vol. 421, January 16, 2003, pp. 241-244.					
	DG	Lieber, C., "The incredible shrinking circuit", <u>Sci. Am.</u> , Vol. 285, September 1, 2001, pp. 58-64.					
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	DJ	Cui Y., et al., "Functional Nanoscale Electronic Devices Assembled Using Silicon Nanowire Building Blocks", <u>Science</u> , Vol. 291, February 2, 2001, pp. 851-853.					
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	DL	Cui Y., et al., "Nanowire nanosensors for highly sensitive and selective detection of biological and chemical species", <u>Science</u> , Vol. 293, August 17, 2001, pp. 1289-1292.					
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	ED	Cui, Y., et al., "Doping and Electrical Transport in Silicon Nanowires", <u>The Journal of Physical Chemistry B</u> , Vol. 104, No. 22, May 11, 2000, pp. 5213-5216.					
	EE	Gudiksen M., et al., "Synthetic Control of the Diameter and Length of Single Crystal Semiconductor Nanowires", <u>The Journal of Physical Chemistry B</u> , Vol. 105, April 18, 2001, pp. 4062-4064.					
	EF	Morales, A. et al., "Rational Synthesis of Silicon Nanowires", <u>INOR</u> , 651, January 1, 2001.					
	EG	Wong E., et al., "Nanobeam Mechanics: Elasticity, Strength, and Toughness of Nanorods and Nanotubes", <u>Science</u> , Vol. 277, September 26, 1997, pp. 1971-1975.					
	EH	Dai, H., et al., "Synthesis and Characterization of Carbide Nanorods", <u>Nature</u> , Vol. 375, June 29, 1995, pp. 769-772.					
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	FD	Thelander, et al., "Gold nanoparticle single-electron transistor with carbon nanotube leads", <u>Applied Physics Letters</u> , Vol. 79, No. 13, September 24, 2001, pp. 2106-2108.					
	FE	Ohlsson B.J, et al., "Size-, shape-, and position-controlled GaAs nano-whiskers", <u>Applied Physics Letters</u> , Vol. 79, No. 20, November 12, 2001, pp. 3335-3337.					
	FF	Bjork, M.T., et al., "One-dimensional heterostructures in semiconductor nanowhiskers", <u>Applied Physics Letters</u> , Vol. 80, No. 6, February 11, 2002, pp. 1058-1060.					
	FG	Persson, M.P. et al., "Electronic Structure of Nanometer-Scale GaAs Whiskers", <u>Applied Physics Letters</u> , Vol. 81, No. 7, August 12, 2002, pp. 1309-1311.					
	FH	Thelander, C., et al., "Single-Electron Transistors in Heterostructure Nanowires", <u>Applied Physics Letters</u> , Vol. 83, No. 10, September 8, 2003, pp. 2052-2054.					
	FI	Panev, N., et al., "Sharp Exciton Emission From Single InAs Quantum Dots in GaAs Nanowires", <u>Applied Physics Letters</u> , Vol. 83, No. 11, September 15, 2003, pp. 2238-2240.					
	FJ	Bjork, M.T., "Nanowire resonant tunnelling diodes", <u>Applied Physics Letters</u> , Vol. 81, No. 23, December 2, 2002, pp. 4458-4460.					
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	GG	Magnusson, M., et al., "Gold nanoparticles: Production, reshaping, and thermal charging", <u>Journal of Nanoparticle Research</u> , Vol. 1, January 1, 1999, pp. 243-251.					
	GH	Samuelson, L., "Self-Forming Nanoscale Devices", <u>Materials Today</u> , October 22, 2003, pp. 22-31.					
	GI	Ohlsson, B., et al., "Fabrication and characterization of III-V nanowhiskers", <u>MSS10 Conference - Austria</u> , July 23-27, 2001.					
	GJ	Bjork, M.T., et al., "One-dimensional Steeplechase for Electrons Realized", <u>Nano Letters</u> , Vol. 2, No. 2, January 19, 2002, pp. 87-89.					
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	HD	Burgess, D.S., "Nanowire Heterostructures Form Tunneling Diodes", <u>Photonics Spectra</u> , Vol. 37, No. 2, pp. 3-5.					
	HE	Pettersson, H., et al., "Electrical and Optical Properties of Self-Assembled InAs Quantum Dots in InP Studied by Space-Charge Spectroscopy and Photoluminescence", <u>Phys. Rev. B</u> , Vol. 61, No. 7, February 15, 2000, pp. 4795-4800.					
	HF	Ohlsson, B.J., et al., "Growth and characterization of GaAs and InAs nano-whiskers and InAs/GaAs heterostructures", <u>Physica E</u> , No. 13, March 1, 2002, pp. 1126-1130.					
	HG	Samuelson, L., et al., "Tunnel-Induced Photon Emission in Semiconductors Using an STM, <u>Physica Scripta</u> , Vol. T42, January 1, 1992, pp. 149-152.					
	HH	Seifert, W. et al, "In-Situ Growth of Quantum Dot Structures by the Stranski-Krastanow Growth Mode", <u>Prog. Crys. Growth Charact.</u> , Vol. 33, January 1, 1996, pp. 423-471.					
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	HJ	Bjork, M., "Semiconductor Nanowires and Devices", Tekn lic thesis, Lund University, November 1, 2002.					
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	IB						
<b>OTHER (including author, title, date, pertinent pages, etc.)</b>							
	IC	Murphy, C.J., et al., "Controlling the Aspect Ratio of Inorganic Nanorods and Nanowires", <u>Advanced Materials</u> , Vol. 14, No. 1, January 4, 2002, pp. 80-82.					
	ID	Wagner, R.S., et al., "Vapour-Liquid-Solid Mechanism of Single Crystal Growth", <u>Appl. Phys. Lett.</u> , Vol. 4, No. 5, March 1, 1964, pp. 89-90.					
	IE	Canham, L.T., "Silicon Quantum Wire Array Fabrication by Electrochemical and Chemical Dissolution of Wafers", <u>Appl. Phys. Lett.</u> , Vol. 57, September 3, 1990, pp. 1046-1048.					
	IF	Koga, T., et al., "Carrier Pocket Engineering Applied to Strained .....", <u>Appl. Phys. Lett.</u> , Vol. 75, October 18, 1999, pp. 2438-2440.					
*	IG	Koga, T., et al., "Experimental Proof-of-Principle Investigation of Enhanced $Z_{sd}T$ in (001) Oriented Si/Ge Superlattices", <u>Appl. Phys. Lett.</u> , Vol. 77, No. 10, September 4, 2000, pp. 1490-1492.					
	IH	Narihiro, M., et al., "Resonant tunneling of electrons via 20 nm scale InAs quantum dot and magnetotunneling spectroscopy of its electronic states", <u>Applied Physics Letters</u> , Vol. 70, No. 1, January 6, 1997, pp. 105-107.					
	II	Pan, Z., et al., "Conduction band offset and electron effective mass in GaInNAs/GaAs quantum-well structures with low nitrogen concentration", <u>Applied Physics Letters</u> , Vol. 78, No. 15, April 9, 2001, pp. 2217-2219.					
	IJ	Ferry, D.K., et al., "Transport in Nanostructures", <u>Cambridge University Press</u> , Hardcover, January 1, 1997, pp. 41-45.					
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<b>OTHER (including author, title, date, pertinent pages, etc.)</b>							
	JC	Ferry, D.K., et al., "Transport in Nanostructures", <u>Cambridge University Press</u> , Hardcover, January 1, 1997, pp. 91-96.					
	JD	Givargizov, E., "Growth of Whiskers by the Vapor-Liquid-Solid Mechanism", <u>Current Topics in Material Science</u> , edited by E. Kaldis, Chapter 3, Vol. 1, January 1, 1978, pp. 79-145.					
	JE	Mullins, J., "News analysis: using unusable frequencies", <u>IEEE Spectrum</u> , Vol. 39, No. 7, July 1, 2002, pp. 22-23.					
	JF	Randall, J.N., et al., "Quantum Dot Devices", in Norman G. Einspruch and William R. Frensley, eds., <u>Heterostructures and Quantum Devices</u> (San Diego, CA: Academic Pres, Inc., 1994) Copyright 1994, p. 420.					
	JG	Markowitz, P.D., et al., "Phase Separation in Al <sub>0.5</sub> Ga <sub>0.5</sub> As Nanowhiskers Grown by the Solution-Liquid-Solid Mechanism", <u>J. Am. Chem. Soc.</u> , Vol. 123, April 18, 2001, pp. 4502-4511.					
	JH	Hickmott, T.W., et al., "Negative Charge, Barrier Heights, and the Conduction-Band Discontinuity in Al <sub>0.5</sub> Ga <sub>0.5</sub> As Capacitors", <u>J. Appl. Phys.</u> , Vol. 57, April 15, 1985, pp. 2844-2853.					
	JI	Mathews, J., et al., "Defects in Epitaxial Multilayers", <u>J. Cryst. Growth</u> , Vol. 27, January 1, 1974, pp. 118-125.					
	JJ	Kovtyukhova, N., et al., "Layer-by-Layer Assembly Rectifying Junctions in and on Metal Nanowires", <u>J. Phys. Chem. B.</u> , Vol. 105, August 14, 2001, pp. 8762-8769.					
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<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	KC	Sakaki, H., "Scattering Suppression and High-Mobility Effect of Size-Quantized Electrons in Ultrafine Semiconductor Wire Structures", <u>Japanese Journal of Applied Physics</u> , Vol. 19, No. 12, December 1, 1980, pp. L735-L738.					
	KD	Scheibel, H. et al., "Generation of Monodisperse Ag- and NaCl Aerosols With Particle Diameters Between 2 and 300 nm", <u>Journal of Aerosol Science</u> , Vol. 14, No. 2, January 1, 1983, pp. 113-126.					
	KE	Knutson, E. et al., "Aerosol Classification by Electric Mobility: Apparatus, Theory, and Applications", <u>Journal of Aerosol Science</u> , Vol. 6, January 1, 1975, pp. 443-451.					
	KF	Miller, M. et al., "Serpentine Superlattice: Concept and First Results", <u>Journal of Crystal Growth</u> , Vol. 111, January 1, 1991, pp. 323-327.					
	KG	Bhat, R., et al., "Patterned Quantum Well Heterostructures Grown by OMCVD on Non-Planar Substrates: Applications to Extremely Narrow SQW Lasers", <u>Journal of Crystal Growth</u> , Vol. 93, January 1, 1988, pp. 850-856.					
	KH	Hara, S., et al., "Formation and Photoluminescence Characterization of Quantum Well Wires Using Multiatomic Steps Grown by Metalorganic Vapor Phase Epitaxy", <u>Journal of Crystal Growth</u> , Vol. 145, January 1, 1994, pp. 692-697.					
	KI	Givargizov, E.I., "Fundamental Aspects of VLS Growth", <u>Journal of Crystal Growth</u> , Vol. 31, January 1, 1975, pp. 20-30.					
	KJ	Derycke, V., et al., "Carbon Nanotube Inter- and Intramolecular Logic Gates", <u>Nano Letters</u> , Vol. 1, No. 9, August 26, 2001, pp. 453-456.					
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<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	LC	Iijima, S., "Helical microtubules of graphitic carbon", <u>Nature</u> , Vol. 354, November 7, 1991, pp. 56-58.					
	LD	Yao, Z., et al., "Carbon Nanotube Intramolecular Junctions", <u>Nature</u> , Vol. 402, November 18, 1999, pp. 273-276.					
	LE	Bennett, C., et al., "Quantum information and computation", <u>Nature</u> , Vol. 404, March 16, 2000, pp. 247-255.					
	LF	Michler, P. et al., "Quantum correlation among photons from a single quantum dot at room temperature", <u>Nature</u> , Vol. 406, No. 6799, August 31, 2000, pp. 968-970.					
	LG	Chow, E., et al., "Three-dimensional control of light in a two-dimensional photonic crystal slab", <u>Nature</u> , Vol. 407, October 26, 2000, pp. 983-986.					
	LH	Venkatasubramanian, R., et al., "Thin-Film Thermoelectric Devices with High Room-Temperature Figures of Merit", <u>Nature</u> , Vol. 413, October 11, 2003, pp. 597-602.					
	LI	Bachtold, A., et al., "Scanned probe microscopy of electronic transport in carbon nanotubes", <u>Phys. Rev. Lett.</u> , Vol. 84, No. 26, June 26, 2000, pp. 6082-6085.					
	LJ	Hicks, L.D. et al., "Thermoelectric Figure of Merit of a One-Dimensional Conductor", <u>Phys. Rev. B</u> , Vol. 47, No. 24, June 15, 1993, pp. 16631-16634.					
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<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	MC	Itskevich, I.E., et al., "Resonant magnetotunneling through individual self-assembled InAs quantum dots", <u>Physical Review B</u> , Vol. 54, No. 23, December 15, 1996, pp. 16401-16404.					
	MD	Reed, M.A., et al., "Observation of Discrete Electronic States in a Zero-Dimensional Semiconductor Nanostructure", <u>Physical Review Letters</u> , Vol. 60, No. 6, February 8, 1988, pp. 535-537.					
	ME	Kapon, E., et al., "Stimulated Emission in Semiconductor Quantum Wire Heterostructures", <u>Physical Review Letters</u> , Vol. 63, No. 4, July 24, 1989, pp. 430-433.					
	MF	Santori, C., et al., "Triggered Single Photons from a Quantum Dot", <u>Physical Review Letters</u> , Vol. 86, No. 8, February 19, 2001, pp. 1502-1505.					
	MG	Capasso, F., et al., "Quantum Cascade Lasers", <u>Physics Today</u> , May 1, 2002, pp. 34-40.					
*	MH	Likharev, K.K., "Single-Electron Devices and their Applications", <u>Proceedings of the IEEE</u> , Vol. 87, No. 4, April 1, 1999, pp. 606-632.					
*	MI	Han, W., et al., "Synthesis of Gallium Nitride Nanorods Through a Carbon Nanotube-Confined Reaction", <u>Science</u> , Vol. 277, August 29, 1997, pp. 1287-1289.					
	MJ	Zhang, Y., et al., "Heterostructures of Single-Walled Carbon Nanotubes and Carbide Nanorods", <u>Science</u> , Vol. 285, September 10, 1999, pp. 1719-1722.					
	MK						
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	NC	<b>Holmes, J., et al., "Control of Thickness and Orientation of Solution-Grown Silicon Nanowires", <u>Science</u>, Vol. 287, February 25, 2000, pp. 1471-1473.</b>					
	ND	<b>Zhou, C.W., et al., "Modulated chemical doping of individual carbon nanotubes", <u>Science</u>, Vol. 290, November 24, 2000, pp. 1552-1555.</b>					
	NE	<b>Favier, F., et al., "Hydrogen Sensors and Switches from Electrodeposited Palladium Mesowire Arrays", <u>Science</u>, Vol. 293, September 21, 2001, pp. 2227-2231.</b>					
	NF	<b>Bachtold, A., et al., "Logic circuits with carbon nanotube transistors", <u>Science</u>, Vol. 294, November 9, 2001, pp. 1317-1320.</b>					
	NG	<b>Nicewarner-Pena, S.R., et al., "Submicrometer metallic barcodes", <u>Science</u>, Vol. 294, October 5, 2001, pp. 137-141.</b>					
	NH	<b>Service, R.F., "Nanowire Fabricators Earn Their Stripes", <u>Science</u>, Vol. 295, No. 5557, January 1, 2002, pp. 946-947.</b>					
	NI	<b>Awschalom, D.D. et al., "Spintronics", <u>Scientific American</u>, Vol. 286, No. 6, June 1, 2002, pp. 66-73.</b>					
	NJ	<b>Henning, P., et al., "Compositional information from amorphous Si-Ge multilayers using high-resolution electron microscopy imaging and direct digital recording", <u>Ultramicroscopy</u>, Vol. 66, January 1, 1996, pp. 221-235.</b>					
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	OB						
<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	OC	Wagner, R.S., "VLS Mechanism of Crystal Growth", <u>Whisker Technology</u> , A.P. Levitt, ed., Chapter 3, January 1, 1970, pp. 47-119.					
	OD	Alferov, Z., et al., "For developing semiconductor heterostructures used in high-speed-and opto-electronics", <u>www.nobel.se.physics/laureates/2000/</u> , November 23, 2000.					
	OE	von Klitzing, K., "for the discovery of the quantized Hall effect", <u>www.nobel.se/physics/laureates/1985/</u> , June 16, 2000.					
	OF	Laughlin, R.B., et al., "For their discovery of a new form of quantum fluid with frictionally charged excitations", <u>www.nobel.se/physics/laureates/1998/</u> , June 16, 2000.					
	OG	Oda, Y., et al., "Natural Formation of Square Scale Structures on Patterned Vicinal Substrates by MOVPE: Application to the Fabrication of Quantum Structures", <u>Phys. Conf. Ser.</u> , No. 166, Chapter 4, August 22-26, 1999, pp. 191-194.					
*	OH	Hayakawa, K., et al., "AlGaAs Nano-Meter Scale Network Structures Fabricated by Selective Area MOVPE", <u>Phys. Conf. Ser.</u> , No. 162, Chapter 8, October 12-16, 1998.					
	OI	Akabori, M. et al., "Selective Area MOVPE Growth of Two-Dimensional Photonic Crystals Having an Air-Hole Array and its Application to Air-Bridge-Type Structures", <u>Physica E</u> , No. 13, January 1, 2002, pp. 446-450.					
	OJ	Melechko, A.V., et al., "Large-Scale Synthesis of Arrays of High-Aspect-Ratio Rigid Vertically Aligned Carbon Nanofibres", <u>Nanotechnology</u> , No. 14, August 19, 2003, pp. 1029-1035.					
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	PB						
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	PC	Kempa, K., et al., "Photonic Crystals Based on Periodic Arrays of Aligned Carbon Nanotubes", <u>Nano Letters</u> , Vol. 3, No. 1, November 19, 2002, pp. 13-18.					
	PD	Takahashi, H., et al., "Formation and Characteristics of 100 nm Scale GaAs Quantum Wires by Selective Area MOVPE", <u>Applied Surface Science</u> , No. 216, January 1, 2003, pp. 402-406.					
	PE	Akabori, M., et al., "InGaAs Nano-Pillar Array Formation on Partially Masked InP(111)B by Selective Area Metal-Organic Vapour Phase Epitaxial Growth for Two-Dimensional Photonic Crystal Application", <u>Nanotechnology</u> , No. 14, August 27, 2003, pp. 1071-1074.					
	PF	Kamins, T.I., et al., "Self-Assembled Silicon Nanowires for Integrating Microsystems, Nanoelectronics and Microelectronics", <u>mstnews</u> , 3/03, March 1, 2003.					
	PG	Wu, Y., et al., "Rational Synthesis of Inorganic Nanowires", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 221, April 1, 2001, pp. 108-1ec Part 1.					
	PH	Yang, P., et al., "Nanowires from Vapor Condensation and their Assemblies", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 219, March 26, 2000, pp. 269-Inor Part 1.					
	PI	Huang, M., et al., "Nanowire Array as Potential 2-d Photonic Bandgap Materials", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 221, April 1, 2001, pp. 95-Phys Part 2.					
	PJ	Yang, P., et al., "Inorganic Nanowires: Rational Synthesis, Functional Assemblies and Novel Properties", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 223, April 7, 2002, pp. 343-Inor Part 2.					
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	QB						
<b>OTHER (including author, title, date, pertinent pages, etc.)</b>							
	QC	Gates, B., et al., "Synthesis and Characterization of Crystalline Ag <sub>2</sub> Se Nanowires through a Template-Engaged Reaction at Room Temperature", <u>Advanced Fun. Materials</u> , Vol. 12, No. 10, October 1, 2002, pp. 679-686.					
	QD	Yang, P., et al., "Controlled Growth of ZnO Nanowires and their Optical Properties", <u>Advanced Functional Materials</u> , Vol. 12, No. 5, May 2002, pp. 323-331.					
	QE	Wu, Y., et al., "Superconducting MgB <sub>2</sub> Nanowires", <u>Advanced Materials</u> , Vol. 13, No. 19, October 2, 2001, pp. 1487-1489.					
	QF	Huang, M., et al., "Catalytic Growth of Zinc Oxide Nanowires by Vapor Transport", <u>Advanced Materials</u> , Vol. 13, No. 2, January 16, 2001, pp. 113-116.					
	QG	Wu, Y., et al., "Melting and Welding Semiconductor Nanowires in Nanotubes", <u>Advanced Materials</u> , Vol. 13, no. 7, April 4, 2001, pp. 520-523.					
	QH	Zhen, B., et al., "Synthesis of Ultra-Long and Highly Oriented Silicon Oxide Nanowires from Liquid Alloys", <u>Advanced Materials</u> , Vol. 14, No. 2, January 16, 2002, pp. 122-124.					
	QI	Kind, H., et al., "Nanowire Ultraviolet Photodetectors and Optical Switches", <u>Advanced Materials</u> , Vol. 14, No. 2, January 16, 2002, pp. 158-160.					
	QJ	Xia, Y., et al., "Chemistry and Physics of Nanowires", <u>Advanced Materials</u> , Vol. 15, No. 5, March 4, 2003, pp. 351-352.					
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<b>FORM PTO-1449</b>				<b>Atty. Docket No.</b> <b>A-9837E</b>		<b>Appln. No.</b> <b>10/613,071</b>	
<b><u>LIST OF DOCUMENTS CITED BY APPLICANT</u></b>							
				<b>Applicant</b> <b>Lars Ivar SAMUELSON et al.</b>			
				<b>Filing Date</b> <b>July 7, 2003</b>		<b>Group</b> <b>2811</b>	
<b>U.S. PATENT DOCUMENTS</b>							
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	RA						
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	RB						
<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	RC	Xia, Y., et al., "One-Dimensional Nanostructures: Synthesis, Characterization, and Applications", <u>Advanced Materials</u> , Vol. 15, No. 5, March 4, 2003, pp. 353-389.					
	RD	Yan, H., et al., "Morphogenesis of One-Dimensional ZnO Nano- and Microcrystals", <u>Advanced Materials</u> , Vol. 15, No. 5, March 4, 2003, pp. 402-405.					
	RE	Wu, Y., et al., "Germanium/Carbon Core-Sheath Nanostructures", <u>Applied Physics Letters</u> , Vol. 77, No. 1, July 3, 2000, pp. 43-45.					
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	RH	Wu, Y., et al., "Direct Observation of Vapor-Liquid-Solid Nanowire Growth", <u>J. Am. Chem. Soc.</u> , Vol. 123, March 13, 2001, p. 3165-3166.					
	RI	Yan, H., et al., "Dendritic Nanowire Ultraviolet Laser Array", <u>J. Am. Chem. Soc.</u> , Vol. 125, No. 16, March 29, 2003, pp. 4728-4729.					
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	SA						
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	SB						
<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	SC	Johnson, J., et al., "Single Nanowire Lasers", <u>Journal of Physical Chemistry B</u> , Vol. 105, No. 46, October 23, 2001, pp. 11387-11390.					
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	SE	Song, J., et al., "MMo <sub>3</sub> Se <sub>3</sub> (M=Li <sup>+</sup> , Na <sup>+</sup> , Rb <sup>+</sup> , Cs <sup>+</sup> , NMe <sub>4</sub> <sup>+</sup> ) Nanowire Formation via Cation Exchange in Organic Solution", <u>Journal of the Amer. Chem. Soc.</u> , Vol. 123, No. 39, March 10, 2001, pp. 9714-9715.					
	SF	Li, Y., et al., "Bismuth Nanotubes: A Rational Low-Temperature Synthetic Route", <u>Journal of the Amer. Chem. Soc.</u> , Vol. 123, No. 40, September 14, 2001, pp. 9904-9905.					
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	TC	Johnson, J., et al., "Single Gallium Nitride Nanowire Lasers", <u>Nature Materials</u> , Vol. 1, No. 2, September 15, 2002, pp. 106-110.					
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	TE	Wu, Y., et al., "Germanium Nanowire Growth via Sample Vapor Transport", <u>Chem. Mater.</u> , Vol. 12, March 20, 2000, pp. 605-607.					
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	TG	Hiruma, K. et al., "GaAs free-standing quantum-size wires", <u>Journal of Applied Physics</u> , Vol. 74, September 1, 1993, pp. 3162-3171.					
	TH	Liu J. L. et al., "Gas-source MBE growth of freestanding Si nanowires on Au/Si substrate", <u>Superlattices Microstructures</u> , 1999, Vol. 25, No. 1-2, pp. 477-479.					
	TI	Shimada et al., "Size, position and direction control on GaAs and InAs nanowhisker growth", <u>Superlattices and Microstructures</u> , Vol. 24, No. 6, December 1998, pp. 453-458					
	TJ	Shirai M., et al., "Gold cluster formation using an atomic force microscope and its applications to GaAs whisker growth", <u>Superlattices and Microstructures</u> , Vol. 24, No. 2, August 1998, pp. 157-162.					
	TK	Hiruma, K. et al., "GaAs and InAs Nanowire Growth Technology", <u>Proceedings of the Science and Technology of Atomically Engineered Materials</u> , October 30, 1995, pp. 563-570					
	TL	Westwater, J. et al., "Control of the size and position of silicon nanowires grown via the vapor-liquid-solid technique", <u>Japanese Journal of Applied Physics</u> , Part 1, October 1997, Vol. 36, pp. 6204-6209					
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